NSN 5961-01-013-0081

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View Online at https://aerobasegroup.com/nsn/5961-01-013-0081 **Inclosure Material:** Metal **Overall Length:** 0.420 inches **Overall Height:** 0.190 inches **Overall Width:** 0.355 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-220ab **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method:** Unthreaded hole **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 60.0 collector to base voltage/static/emitter open and 50.0 collector-to-emitter, substaining voltage, base open-circuited and 5.0 emitter to base voltage, static, collector open **Current Rating Per Characteristic:** Between 3.00 amperes source cutoff current and 7.00 amperes source cutoff current **Power Rating Per Characteristic:** 40.0 watts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius junction **Special Features:** Junction pattern arrangement: npn **Terminal Type And Quantity:** 3 tab, solder lug **Specification Data:** 80131-release6336 professional/industrial association specification Shelf Life: N/a **Unit Of Measure:**

No

Demilitarization:

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